

## **KSA539**

## **Low Frequency Amplifier**

- Complement to KSC815
- Collector-Base Voltage: V<sub>CBO</sub> = -60V
- Collector Power Dissipation: P<sub>C</sub> = 400mW
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



## **PNP Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-45	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-200	mA
P <sub>C</sub>	Collector Power Dissipation	400	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-60			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C$ = -10mA, $I_B$ =0	-45			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = -10\mu A, I_C = 0$	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ = -45V, $I_{E}$ =0			-100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ = -3V, $I_{C}$ =0			-100	nA
h <sub>FE</sub>	DC Current Gain	$V_{CE}$ = -1V $I_{C}$ = -50mA	40		240	
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE}$ = -1V, $I_{C}$ = -10mA	-0.60	-0.65	-0.90	V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -150mA, I <sub>B</sub> = -15mA		-0.25	-0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -150mA, I <sub>B</sub> = -15mA		-0.9	-1.2	V

## **h**<sub>FE</sub> Classification

Classification	R	0	Y
h <sub>FE</sub>	40 ~ 80	70 ~ 140	120 ~ 240

# **Typical Characteristics**

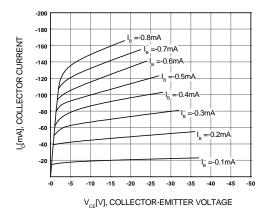


Figure 1. Static Characteristic

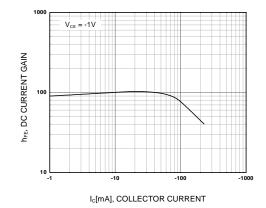


Figure 2. DC current Gain

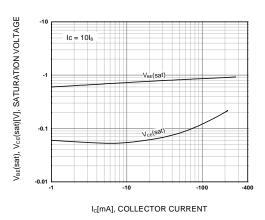


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

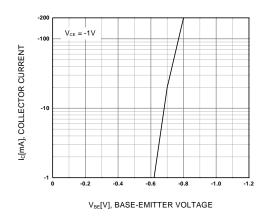


Figure 4. Base-Emitter On Voltage

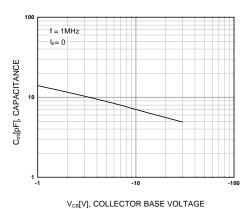
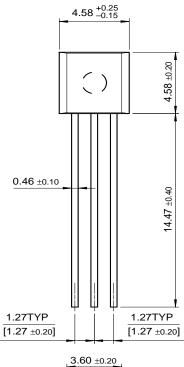


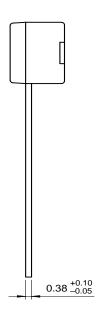
Figure 5. Collector Output Capacitance

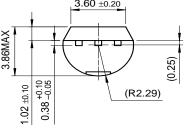
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## **Package Demensions**

TO-92







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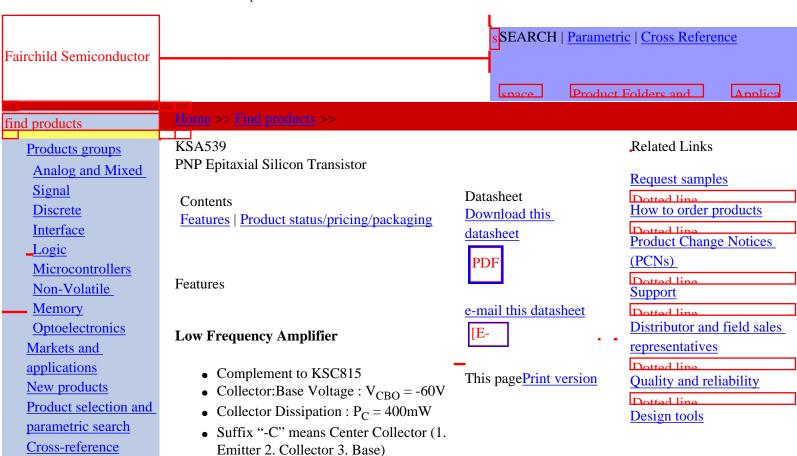
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSA539YTA	Full Production	\$0.058	<u>TO-92</u>	3	TAPE REEL
KSA539CYTA	Full Production	\$0.058	<u>TO-92</u>	3	TAPE REEL
KSA539OTA	Full Production	\$0.058	<u>TO-92</u>	3	TAPE REEL
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